

MCS2400X
MCS2400, MCS2



**PHOTON COUPLED ISOLATOR Ga As
INFRARED EMITTING DIODE &
LIGHT ACTIVATED SCR**

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 2 available lead forms : -
- STD
- G form

DESCRIPTION

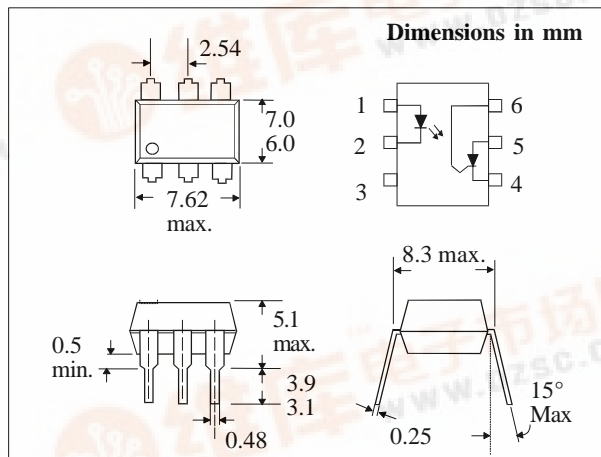
The MCS2, MCS2400 are optically coupled isolators consisting of infrared light emitting diode and a light activated silicon controlled rectifier in a standard 6pin dual in line plastic package.

FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High Surge Anode Current (5.0 A)
- High Blocking Voltage (200V*1, 400V*1)
- Low Turn on Current (5mA typical)
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- 10A, T²L compatible, Solid State Relay
- 25W Logic Indicator Lamp Driver
- 400V Symmetrical transistor coupler



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

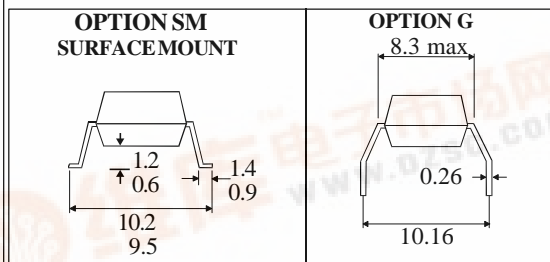
INPUT DIODE

Forward Current	60mA
Forward Current (Peak) (1µs pulse, 300pps)	3A
Reverse Voltage	6V
Power Dissipation	100mW

DETECTOR

Peak Forward Voltage MCS2	200V*1
MCS2400	400V*1
Peak Reverse Gate Voltage	6V
RMS On-state Current	300mA
Peak On-state Current (100µs, 1% duty cycle)	10A
Surge Current (10ms)	5A
Power Dissipation	300mW

*1 IMPORTANT : A resistor must be connected between gate and cathode (pins 4 & 6) to prevent false firing ($R_{GK} < 56k\Omega$)



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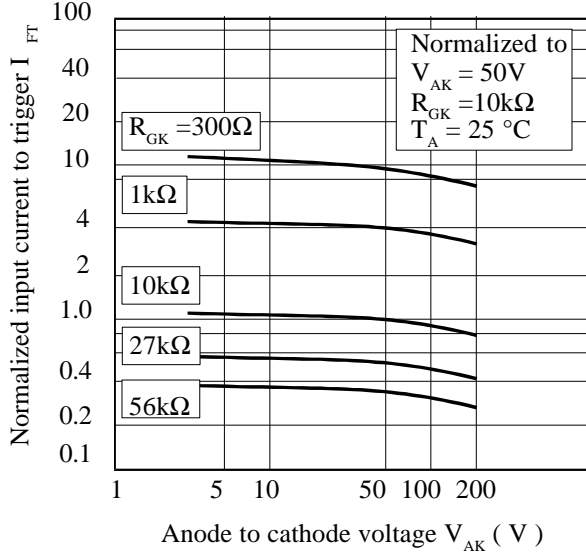
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	$I_F = 20\text{mA}$
	Reverse Voltage (V_R)	3			V	$I_R = 10\mu\text{A}$
Output (note 2)	Peak Off-state Voltage (V_{DM}) MCS2	200			V	$R_{GK}=10\text{k}\Omega, I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	MCS2400	400			V	$R_{GK}=10\text{k}\Omega, I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	Peak Reverse Voltage (V_{RM}) MCS2	200			V	$I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	MCS2400	400			V	$I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	On-state Voltage (V_{TM})		1.1	1.3	V	$I_{TM} = 100\text{mA}$
	Off-state Current (I_{DM}) MCS2			2	μA	$R_{GK}=27\text{k}\Omega, I_F = 0, V_{DM} = 200\text{V}$
	MCS2400			2	μA	$R_{GK}=27\text{k}\Omega, I_F = 0, V_{DM} = 400\text{V}$
	Reverse Current (I_R) MCS2			2	μA	$I_F = 0, V_{DM} = 200\text{V}$
	MCS2400			2	μA	$I_F = 0, V_{DM} = 400\text{V}$
	Holding Current (I_H)	10		500	μA	$R_{GK}=27\text{k}\Omega, V_{FX}=50\text{V}$
Coupled	Input Current to Trigger (I_{FT}) (note 2)	0.5		14	mA	$V_{AK}=100\text{V}, R_{GK}=27\text{k}\Omega$
	Turn on Time (t_{on})			50	μs	$R_{GK}=10\text{k}\Omega, I_F=30\text{mA}, V_{AK}=50\text{V}, R_L=200\Omega$
	Coupled dv/dt, Input to Output (dv/dt)	500			V/ μs	
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO} Input-output Capacitance C_f	10^{11}		2	Ω pF	$V_{IO} = 500\text{V}$ (note 1) $V = 0, f = 1\text{MHz}$

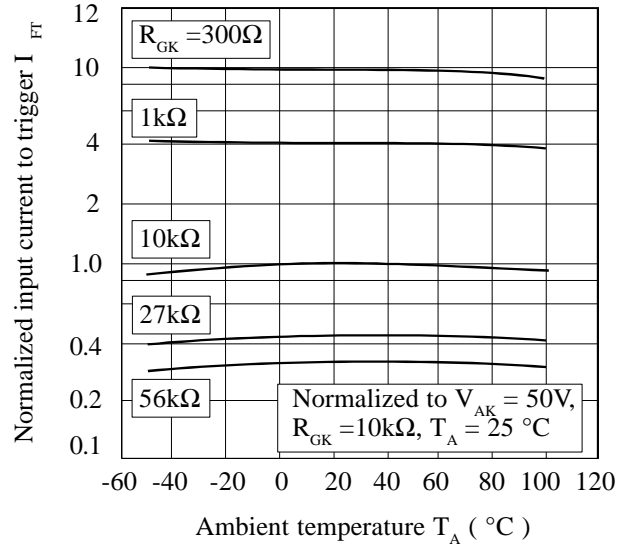
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

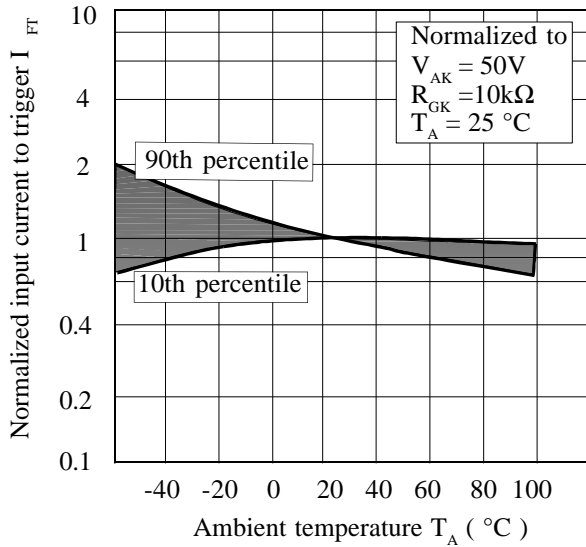
Input Current to Trigger vs. Anode to Cathode Voltage



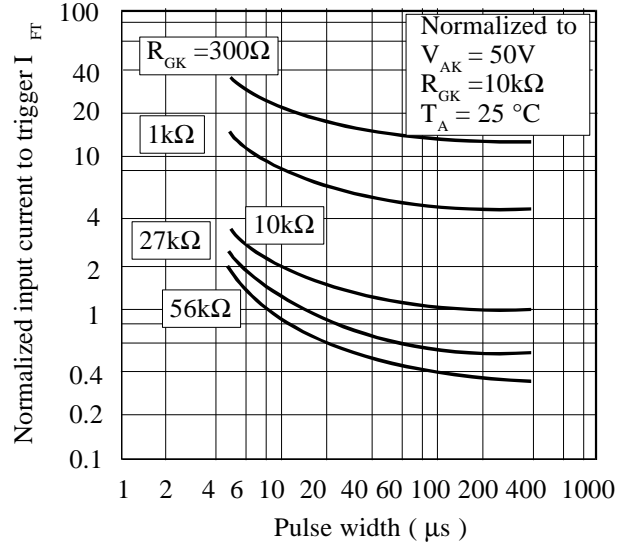
Input Current to Trigger vs. Ambient Temperature



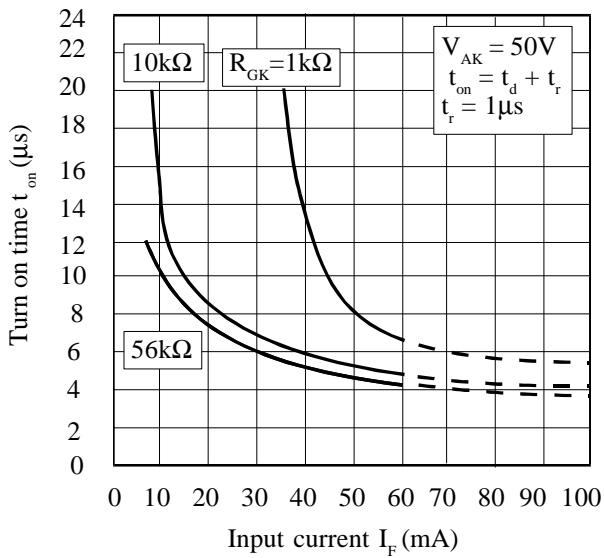
Input Current to Trigger Distribution vs. Ambient Temperature



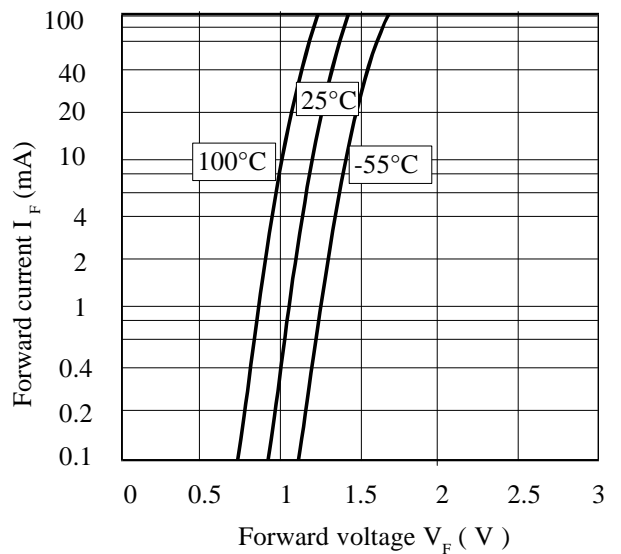
Input Current to Trigger vs. Pulse Width



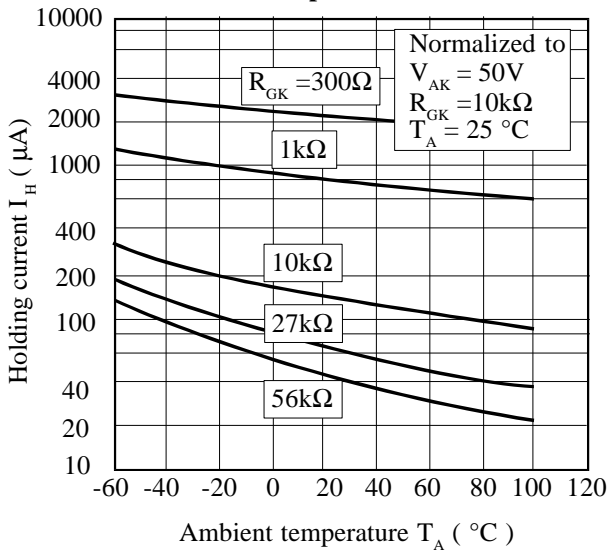
Turn on Time vs. Input Current



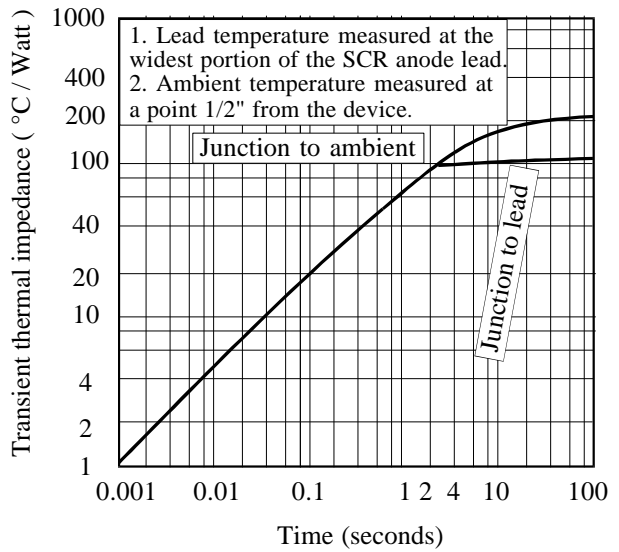
Input Characteristics I_F vs. V_F



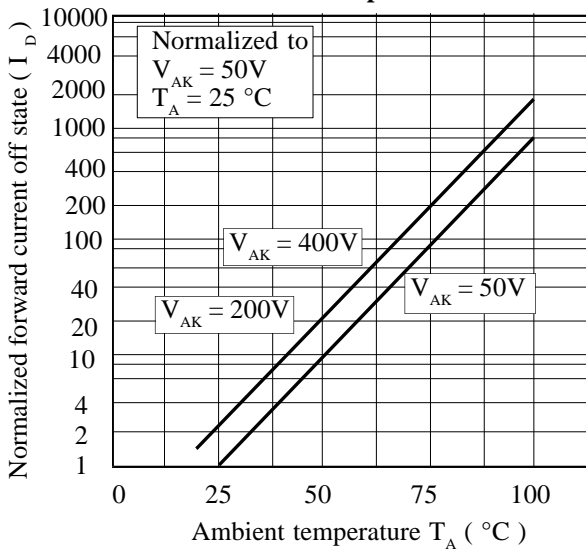
Holding Current vs. Ambient Temperature



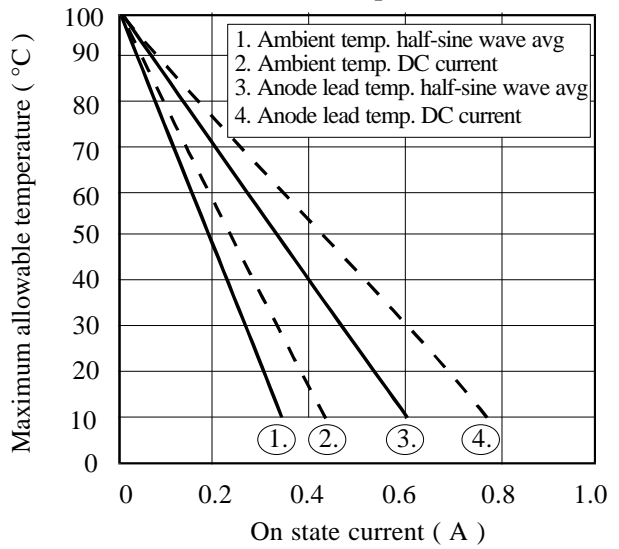
Maximum Transient Thermal Impedance



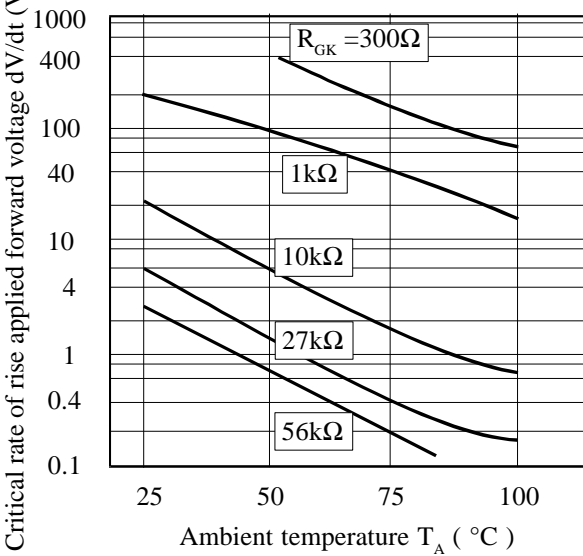
Off State Forward Current vs. Ambient Temperature



On State Current vs. Maximum Allowable Temperature



dV/dt vs. Ambient temperature



On State Characteristics

